

RoHS Compliant Product

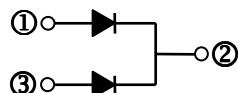
A suffix of "C" specifies halogen free

FEATURES

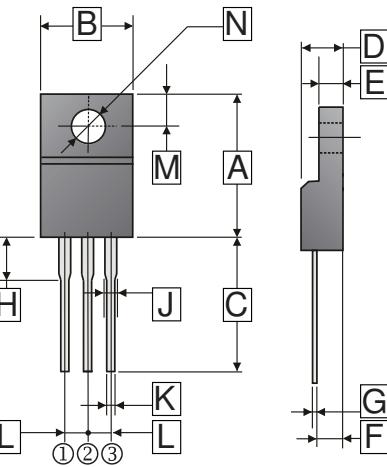
- Trench MOS Schottky technology
- Low forward voltage drop
- Low reverse current
- High current capability
- High reliability
- High surge current capability
- Epitaxial construction

MECHANICAL DATA

- Case: Molded plastic
- Epoxy: UL94V-0 rate flame retardant
- Lead: Lead solderable per MIL-STD-202 method 208 guaranteed
- Polarity: As Marked
- Mounting position: Any
- Weight: 1.98 g (Approximate)



ITO-220



REF.	Millimeter		REF.	Millimeter	
	Min.	Max.		Min.	Max.
A	14.60	15.70	H	2.70	4.00
B	9.50	10.50	J	0.90	1.50
C	12.60	14.00	K	0.50	0.90
D	4.30	4.70	L	2.34	2.74
E	2.30	3.2	M	2.40	3.00
F	2.30	2.90	N	Ø 3.0	Ø 3.4
G	0.30	0.75			

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Rating 25°C ambient temperature unless otherwise specified. Single phase half wave, 60Hz, resistive or inductive load.
For capacitive load, de-rate current by 20%).

Parameter	Symbol	Rating	Unit
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	120	V
Working Peak Reverse Voltage	V _{RSM}	120	V
Maximum DC Blocking Voltage	V _{DC}	120	V
Maximum Average Forward Rectified Current (Per Leg)	I _F	10	A
(Per Device)	I _F	20	
Peak Forward Surge Current, 8.3 ms single half sine-wave	I _{FSM}	150	A
Voltage Rate of Change (Rated V _R)	dv/dt	10000	V / µs
Typical Thermal Resistance	R _{θJC}	4	°C /W
Operating and Storage Temperature Range	T _J , T _{STG}	-40~150	°C

ELECTRICAL CHARACTERISTICS

Parameter	Symbol	Typ.	Max.	Unit	Test Condition
Maximum Instantaneous Forward Voltage	V _F	0.66	0.7	V	I _F = 3A, T _J = 25°C
		0.71	0.75		I _F = 5A, T _J = 25°C
		0.8	0.85		I _F = 10 A, T _J = 25°C
		0.65	-		I _F = 10 A, T _J = 125°C
Maximum DC Reverse Current at Rated DC Blocking Voltage ²	I _R	-	0.1	mA	T _J =25°C
		-	10		T _J =100°C
Typical Junction Capacitance ¹	C _J	210	-	pF	

NOTES:

1. Measured at 1MHz and applied reverse voltage of 5.0V D.C.
2. Pulse Test : Pulse Width = 300 µs, Duty Cycle ≤ 2.0%.

RATINGS AND CHARACTERISTIC CURVES

